TLE5012BD
GMR-Based Angle Sensor

1 Overview

Features

• Giant Magneto Resistance (GMR)-based principle
• Fully redundant design with two sensor ICs in one package
• Integrated magnetic field sensing for angle measurement
• 360° angle measurement with revolution counter and angle speed measurement
• Two separate highly accurate single bit SD-ADC
• 15 bit representation of absolute angle value on the output (resolution of 0.01°)
• 16 bit representation of sine / cosine values on the interface
• Max. 1.0° angle error over lifetime and temperature-range with activated auto-calibration
• Bi-directional SSC Interface up to 8 Mbit/s
• Supports Safety Integrity Level (SIL) with diagnostic functions and status information
• Interfaces: SSC, PWM, Incremental Interface (IIF), Hall Switch Mode (HSM), Short PWM Code (SPC, based on SENT protocol defined in SAE J2716)
• Output pins can be configured (programmed or pre-configured) as push-pull or open-drain
• Bus mode operation of multiple sensors on one line is possible with SSC or SPC interface
• 0.25 µm CMOS technology
• Automotive qualified: -40°C to 150°C (junction temperature)
• ESD > 4 kV (HBM)
• RoHS compliant (Pb-free package)
• Halogen-free

PRO-SIL™ Features

• Test vectors switchable to ADC input (activated via SSC interface)
• Inversion or combination of filter input streams (activated via SSC interface)
• Data transmission check via 8-bit Cyclic Redundancy Check (CRC) for SSC communication and 4-bit CRC nibble for SPC interface
• Built-in Self-test (BIST) routines for ISM, CORDIC, CCU, ADCs run at startup
• Two independent active interfaces possible
• Overvoltage and undervoltage detection
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Overview

Potential applications
The TLE5012BD GMR-based angle sensor is designed for angular position sensing in automotive applications such as:

- Electrical commutated motor (e.g. used in Electric Power Steering (EPS))
- Steering angle measurements
- General angular sensing

Product validation
Qualified for automotive applications. Product validation according to AEC-Q100.

About this document
This document is an addendum to the TLE5012B datasheet and describes the TLE5012BD dual die angle sensor. For all parameters which are not specified here, the TLE5012B datasheet is valid.

Description
The TLE5012BD is a 360° angle sensor that detects the orientation of a magnetic field. This is achieved by measuring sine and cosine angle components with monolithic integrated Giant Magneto Resistance (IGMR) elements. These raw signals (sine and cosine) are digitally processed internally to calculate the angle orientation of the magnetic field (magnet).

The TLE5012BD is a pre-calibrated sensor. The calibration parameters are stored in laser fuses. At start-up the values of the fuses are written into flip-flops, where these values can be changed by the application-specific parameters. Further precision of the angle measurement over a wide temperature range and a long lifetime can be improved by enabling an optional internal autocalibration algorithm.

Data communications are accomplished with a bi-directional Synchronous Serial Communication (SSC) that is SPI-compatible. The sensor configuration is stored in registers, which are accessible by the SSC interface. Additionally four other interfaces are available with the TLE5012BD: Pulse-Width-Modulation (PWM) Protocol, Short-PWM-Code (SPC) Protocol, Hall Switch Mode (HSM) and Incremental Interface (IIF). These interfaces can be used in parallel with SSC or alone. Pre-configured sensor derivates with different interface settings are available.

Table 1 Derivate ordering codes

<table>
<thead>
<tr>
<th>Product type</th>
<th>Marking</th>
<th>Ordering code</th>
<th>Package</th>
</tr>
</thead>
<tbody>
<tr>
<td>TLE5012BD E1200</td>
<td>121200</td>
<td>SP001205296</td>
<td>PG-TDSO-16</td>
</tr>
<tr>
<td>TLE5012BD E9200</td>
<td>129200</td>
<td>SP001205300</td>
<td>PG-TDSO-16</td>
</tr>
</tbody>
</table>
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## 2 Pin Configuration

![Pin configuration (top view)](image)

### 2.1 Pin Description

<table>
<thead>
<tr>
<th>Pin No.</th>
<th>Symbol</th>
<th>In/Out</th>
<th>Function</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>IFC1</td>
<td>I/O</td>
<td>Die 1 Interface C: External Clock(^1)/IIF Index/Hall Switch Signal 3</td>
</tr>
<tr>
<td></td>
<td>(CLK / IIF_IDX / HS3)</td>
<td></td>
<td></td>
</tr>
<tr>
<td>2</td>
<td>SCK1</td>
<td>I</td>
<td>Die 1 SSC Clock</td>
</tr>
<tr>
<td>3</td>
<td>CSQ1</td>
<td>I</td>
<td>Die 1 SSC Chip Select</td>
</tr>
<tr>
<td>4</td>
<td>DATA1</td>
<td>I/O</td>
<td>Die 1 SSC Data</td>
</tr>
<tr>
<td>5</td>
<td>DATA2</td>
<td>I/O</td>
<td>Die 2 SSC Data</td>
</tr>
<tr>
<td>6</td>
<td>CSQ2</td>
<td>I</td>
<td>Die 2 SSC Chip Select</td>
</tr>
<tr>
<td>7</td>
<td>SCK2</td>
<td>I</td>
<td>Die 2 SSC Clock</td>
</tr>
<tr>
<td>8</td>
<td>IFC2</td>
<td>I/O</td>
<td>Die 2 Interface C: External Clock(^1)/IIF Index/Hall Switch Signal 3</td>
</tr>
<tr>
<td></td>
<td>(CLK / IIF_IDX / HS3)</td>
<td></td>
<td></td>
</tr>
<tr>
<td>9</td>
<td>IFB2</td>
<td>O</td>
<td>Die 2 Interface B: IIF Phase B/Hall Switch Signal 2</td>
</tr>
<tr>
<td></td>
<td>(IIF_B / HS2)</td>
<td></td>
<td></td>
</tr>
<tr>
<td>10</td>
<td>GND2</td>
<td>-</td>
<td>Die 2 Ground</td>
</tr>
<tr>
<td>11</td>
<td>VDD2</td>
<td>-</td>
<td>Die 2 Supply Voltage</td>
</tr>
</tbody>
</table>
Dual Die Angle Output

The bottom sensor element of the TLE5012BD is flipped relative to the orientation of the top sensor element. Therefore, the rotation direction sensed by the bottom element is opposite to the top element. This is advantageous for safety critical applications, as the two sensor elements do generally not output the same angle. Figure 2 shows the output of the two sensor ICs for a given external magnetic field orientation.

For applications where an identical angle output of both ICs is desired, the rotation direction and angle offset of one sensor IC can be reconfigured by changing the settings in the ANG_BASE and ANG_DIR registers via SSC interface.
4 Specification

4.1 Absolute Maximum Ratings

Table 3 Absolute maximum ratings

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Symbol</th>
<th>Values</th>
<th>Unit</th>
<th>Note or Test Condition</th>
</tr>
</thead>
<tbody>
<tr>
<td>Ambient temperature</td>
<td>$T_A$</td>
<td>-40°C</td>
<td>125°C</td>
<td>qualification acc. to AEC Q100 grade 1</td>
</tr>
<tr>
<td>Junction temperature</td>
<td>$T_J$</td>
<td>-40°C</td>
<td>150°C</td>
<td>For 1000 h, not additive</td>
</tr>
</tbody>
</table>

Attention: Stresses above the max. values listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Maximum ratings are absolute ratings; exceeding only one of these values may cause irreversible damage to the device.

Table 4 ESD protection

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Symbol</th>
<th>Values</th>
<th>Unit</th>
<th>Notes</th>
</tr>
</thead>
<tbody>
<tr>
<td>ESD voltage</td>
<td>$V_{HBM}$</td>
<td>±4.0 kV</td>
<td>1)</td>
<td>ground pins connected</td>
</tr>
<tr>
<td></td>
<td>$V_{HBM}$</td>
<td>±2.0 kV</td>
<td>1)</td>
<td></td>
</tr>
<tr>
<td></td>
<td>$V_{CDM}$</td>
<td>±0.5 kV</td>
<td>2)</td>
<td></td>
</tr>
<tr>
<td></td>
<td>$V_{CDM}$</td>
<td>±0.75 kV</td>
<td>2)</td>
<td>for corner pins</td>
</tr>
</tbody>
</table>

1) Human Body Model (HBM) according to ANSI/ESDA/JEDEC JS-001
2) Charged Device Model (CDM) according to JESD22-C101

4.2 Characteristics

4.2.1 Input/Output characteristics

The indicated parameters apply to the full operating range, unless otherwise specified. The typical values correspond to a supply voltage $V_{DD} = 5.0$ V and 25°C, unless individually specified. All other values correspond to $-40° < T_J < 150°C$.

Table 5 Electrical parameters for $4.5 < V_{DD} < 5.5$ V

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Symbol</th>
<th>Values</th>
<th>Unit</th>
<th>Note or Test Condition</th>
</tr>
</thead>
<tbody>
<tr>
<td>Input signal low-level</td>
<td>$V_{LS}$</td>
<td>0.3 $V_{DD}$</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>Input signal high level</td>
<td>$V_{HS}$</td>
<td>0.7 $V_{DD}$</td>
<td>V</td>
<td></td>
</tr>
</tbody>
</table>
4.3 Calculation of the Junction Temperature

The total power dissipation $P_{TOT}$ of the chips leads to self-heating, which increases the junction temperature $T_J$ above the ambient temperature.
The power multiplied by the total thermal resistance $R_{\text{thJA}}$ (junction to ambient) yields the junction temperature. $R_{\text{thJA}}$ is the sum of the two components Junction to Case and Case to Ambient.

$$R_{\text{thJA}} = R_{\text{thJC}} + R_{\text{thCA}} \quad (4.1)$$

$$T_J = T_A + \Delta T$$

$$\Delta T = R_{\text{thJA}} \times P_{\text{TOT}} = R_{\text{thJA}} \times (V_{\text{DD}} \times 2I_{\text{DD}} + \sum Q V_Q \times 2I_Q) \quad (I_{\text{DD}}, I_Q > 0, \text{if direction is into IC})$$

Factors of 2 in the calculation account for the two sensor ICs in the TLE5012BD. Example (assuming no load on $V_{\text{out}}$).

$$V_{\text{DD}} = 5V \quad (4.2)$$

$$2I_{\text{DD}} = 28 mA$$

$$\Delta T = 120 \left[ \frac{K}{W} \right] \times (5[V] \times 0.028[A] + 0[V\cdot A]) = 16.8K$$

For molded sensors, the calculation with $R_{\text{thJC}}$ is more appropriate.
Pre-Configured Derivates

5 Pre-Configured Derivates

Derivates of the TLE5012BD are available with different pre-configured register settings for specific applications. The configuration of all derivates can be changed via SSC interface. A detailed table of settings of the derivates can be found in the latest TLE5012B Register Setting User Manual.

5.1 IIF-type: E1200
The TLE5012BD-E1200 is preconfigured for Incremental Interface and fast angle update rate (42.7 μs). It is most suitable for BLDC motor commutation.
- Autocalibration mode 1 enabled.
- Prediction disabled.
- Hysteresis is set to 0.625°.
- 12bit mode, one count per 0.088° angle step.
- Incremental Interface A/B mode.

5.2 SPC-type: E9200
The TLE5012BD-E9200 is preconfigured for Short-PWM-Code interface. It is most suitable for steering angle and actuator position sensing.
- Angle update time is 85.4 μs.
- Autocalibration, Prediction, and Hysteresis are disabled.
- SPC unit time is 3 μs.
- SPC interface is set to open-drain output.
6 Package Information

6.1 Package Parameters

Table 7 Package Parameters

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Symbol</th>
<th>Limit Values</th>
<th>Unit</th>
<th>Notes</th>
</tr>
</thead>
<tbody>
<tr>
<td>Thermal resistance(^1)</td>
<td>R(_{th,JA})</td>
<td>120 140</td>
<td>K/W</td>
<td>Junction to air(^2)</td>
</tr>
<tr>
<td></td>
<td>R(_{th,JC})</td>
<td>35</td>
<td>K/W</td>
<td>Junction to case</td>
</tr>
<tr>
<td></td>
<td>R(_{th, JL})</td>
<td>70</td>
<td>K/W</td>
<td>Junction to lead</td>
</tr>
<tr>
<td>Moisture Sensitivity Level</td>
<td>MSL 3</td>
<td></td>
<td></td>
<td>260°C</td>
</tr>
<tr>
<td>Lead Frame</td>
<td>Cu</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Plating</td>
<td>Sn 100%</td>
<td></td>
<td>&gt; 7 (\mu)m</td>
<td></td>
</tr>
</tbody>
</table>

\(^1\) R\(_{th}\) values only valid for both dies supplied with V\(_{DD}\)

\(^2\) according to Jedec JESD51-7

6.2 Package Outline

Figure 3 PG-TDSO-16 package dimension
Figure 4  Position of sensing element, reference to package
Figure 5  Position of sensing element, reference to lead frame

Table 8  Sensor IC placement tolerances in package

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Values</th>
<th>Unit</th>
<th>Notes</th>
</tr>
</thead>
<tbody>
<tr>
<td>position eccentricity</td>
<td>-100</td>
<td>100 µm</td>
<td>in X- and Y-direction, reference to package</td>
</tr>
<tr>
<td>position eccentricity</td>
<td>-150</td>
<td>150 µm</td>
<td>in X-direction, reference to lead frame</td>
</tr>
<tr>
<td>position eccentricity</td>
<td>-200</td>
<td>200 µm</td>
<td>in Y-direction, reference to lead frame</td>
</tr>
<tr>
<td>rotation</td>
<td>-3</td>
<td>3 °</td>
<td>affects zero position offset of sensor</td>
</tr>
<tr>
<td>tilt</td>
<td>-3</td>
<td>3 °</td>
<td></td>
</tr>
</tbody>
</table>
6.3 Footprint

![Figure 6 Footprint of PG-TDSO-16](image)

6.4 Packing

![Figure 7 Tape and Reel](image)

6.5 Marking

The device is marked on the frontside with a date code, the device type and a lot code. On the backside is a 8 x 18 data matrix code.

<table>
<thead>
<tr>
<th>Position</th>
<th>Marking</th>
<th>Description</th>
</tr>
</thead>
<tbody>
<tr>
<td>1st Line</td>
<td>Gxxxx</td>
<td>G = green, 4-digit = date code</td>
</tr>
<tr>
<td>2nd Line</td>
<td>12x200</td>
<td>Type (6 digits), See ordering Table 1</td>
</tr>
<tr>
<td>3rd Line</td>
<td>xxx</td>
<td>Lot code (3 digits)</td>
</tr>
</tbody>
</table>

*Note: For processing recommendations, please refer to Infineon’s Notes on processing*
Figure 8  Marking
## Revision history

<table>
<thead>
<tr>
<th>Revision</th>
<th>Date</th>
<th>Changes</th>
</tr>
</thead>
<tbody>
<tr>
<td>Rev. 1.3</td>
<td>2019-02-05</td>
<td>New Template/New Logo</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Update Electrical parameters: $V_{H3}$ for IFC pin</td>
</tr>
</tbody>
</table>
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